

Features

- $I_{F(AV)}$ 3A
- V_{RRM} 50V-1000V
- High surge current capability
- Polarity: Color band denotes cathode



Applications

- Rectifier

Marking

- US3X
- X : From A To M

SMB top view

Schematic diagram



Halogen-Free

Limiting Values(Absolute Maximum Rating)

Symbol	Parameter	Test Conditions	US3							Unit
			A	B	D	G	J	K	M	
V_{RRM}	Repetitive Peak Reverse Voltage		50	100	200	400	600	800	1000	V
V_{RMS}	Maximum RMS voltage		35	70	140	280	420	560	700	V
$I_{F(AV)}$	Average Forward Current	60Hz Half-sine wave Resistance load	3.0						A	
I_{FSM}	Surge(Non-repetitive)Forward Current	60Hz Half-sine wave, 1 cycle, $T_a=25^\circ C$	100						A	
T_j, T_{stg}	Storage Temperature Range		-55~+150						$^\circ C$	

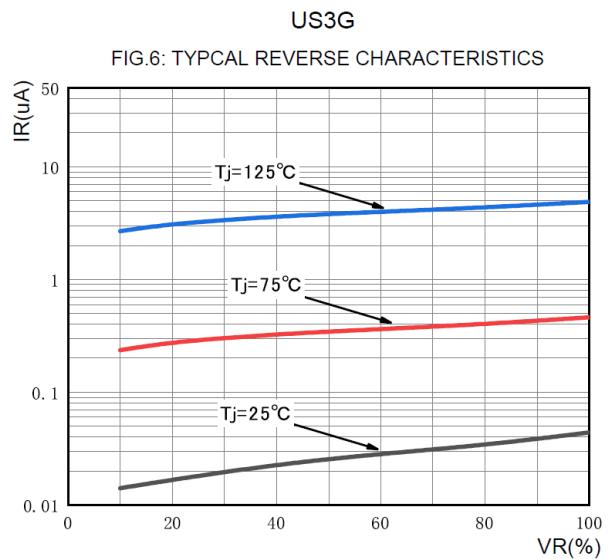
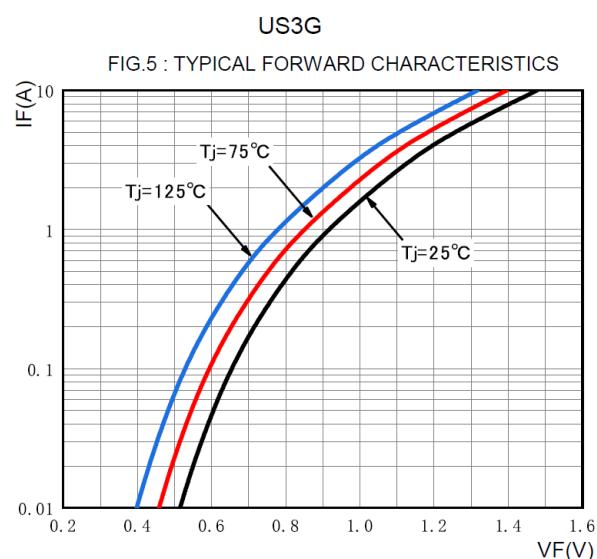
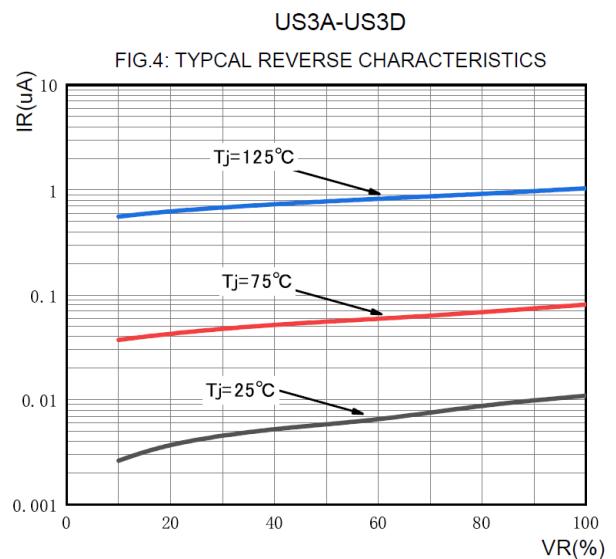
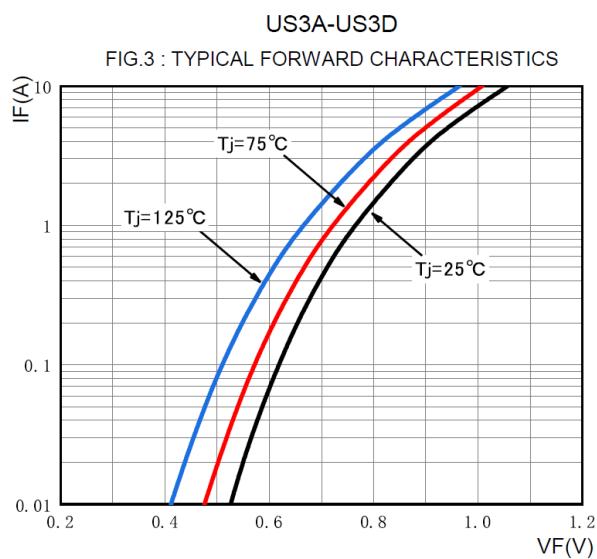
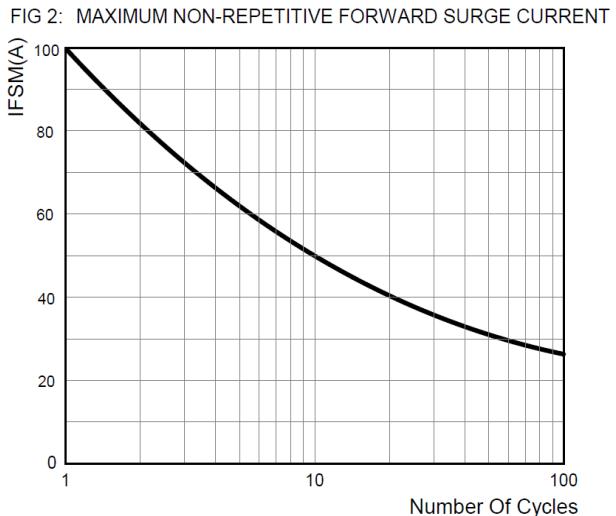
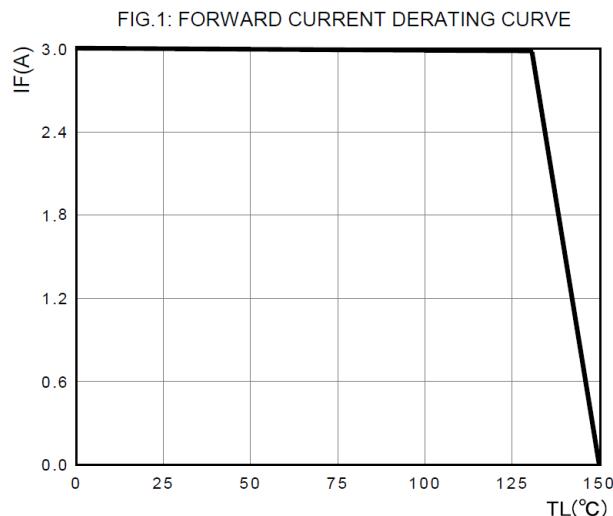
Electrical Characteristics (T=25°C Unless otherwise specified)

Item	Symbol	Condition	US3							Unit
			A	B	D	G	J	K	M	
Peak Forward Voltage	V_F	$I_F = 3.0A$	1.0		1.3	1.7				V
Maximum reverse recovery time	t_{rr}	$I_F=0.5A, I_R=1.0A, I_{rr}=0.25A$	50			75				ns
Peak Reverse Current	I_{RRM1}	$V_{RM}=V_{RRM} T_a=25^\circ C$	5						μA	
	I_{RRM2}	$V_{RM}=V_{RRM} T_a=125^\circ C$	50							
Thermal Resistance(Typical)	$R_{\theta J-A}$	Between junction and ambient	65						$^\circ C/W$	
	$R_{\theta J-L}$	Between junction and terminal	13							
Junction Capacitance (Typical)	C_J	Measured at 1MHZ and Applied Rever Voltage of 4.0 V.D.C	60		30	23			pF	

Notes:

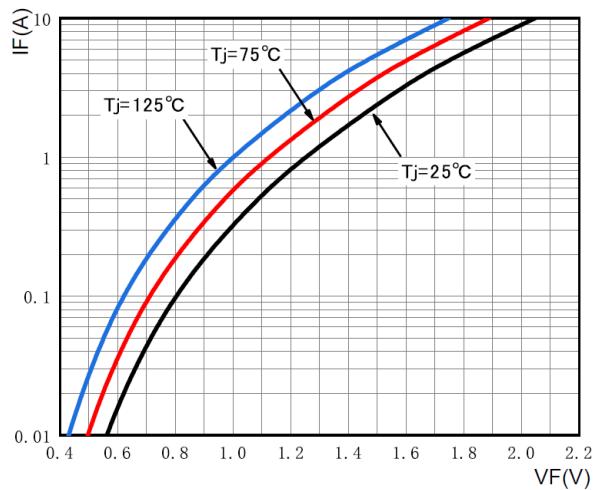
Thermal resistance from junction to ambient and from junction to lead mounted on 1" x 1"(25.4mm x 25.4mm) FR4 PCB, double sided copper, with minimum pad layout

Typical Characteristics



US3J-US3M

FIG.7 : TYPICAL FORWARD CHARACTERISTICS



US3J-US3M

FIG.8: TYPICAL REVERSE CHARACTERISTICS

